# NSDEMN11XV6T1, NSDEMN11XV6T5

# Common Cathode Quad Array Switching Diode

This Common Cathode Epitaxial Planar Quad Diode is designed for use in ultra high speed switching applications. This device is housed in the SOT–563 package which is designed for low power surface mount applications, where board space is at a premium.

#### **Features**

- Fast t<sub>rr</sub>
- Low C<sub>D</sub>
- Pb-Free Packages are Available

### **MAXIMUM RATINGS** $(T_A = 25^{\circ}C)$

Rating	Symbol	Value	Unit
Reverse Voltage	V <sub>R</sub>	80	Vdc
Peak Reverse Voltage	V <sub>RM</sub>	80	Vdc
Forward Current	lF	100	mAdc
Peak Forward Current	I <sub>FM</sub>	300	mAdc
Peak Forward Surge Current	I <sub>FSM</sub> (Note 1)	2.0	Adc

## THERMAL CHARACTERISTICS

Characteristic (One Junction Heated)	Symbol	Max	Unit
Total Device Dissipation @T <sub>A</sub> = 25°C  Derate above 25°C	P <sub>D</sub>	357 (Note 2) 2.9 (Note 2)	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	350 (Note 2)	°C/W
Characteristic (Both Junctions Heated)	Symbol	Max	Unit
Total Device Dissipation @T <sub>A</sub> = 25°C  Derate above 25°C	P <sub>D</sub>	500 (Note 2) 4.0 (Note 2)	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	250 (Note 2)	°C/W
Junction and Storage Temperature	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

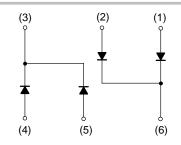
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- 1.  $t = 1 \mu S$
- 2. FR-4 @ Minimum Pad



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SOT-563 CASE 463A PLASTIC

#### **MARKING DIAGRAM**



N9 = Specific Device Code

M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

## **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NSDEMN11XV6T1	SOT-563	4000/Tape & Reel
NSDEMN11XV6T1G	SOT-563 (Pb-Free)	4000/Tape & Reel
NSDEMN11XV6T5	SOT-563	8000/Tape & Reel
NSDEMN11XV6T5G	SOT-563 (Pb-Free)	8000/Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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## **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C)

Characteristic	Symbol	Condition	Min	Max	Unit
Reverse Voltage Leakage Current	I <sub>R</sub>	V <sub>R</sub> = 70 V	_	0.1	μAdc
Forward Voltage	V <sub>F</sub>	I <sub>F</sub> = 100 mA	_	1.2	Vdc
Reverse Breakdown Voltage	V <sub>R</sub>	I <sub>R</sub> = 100 μA	80	_	Vdc
Diode Capacitance	C <sub>D</sub>	$V_R = 6.0 \text{ V}, f = 1.0 \text{ MHz}$	-	3.5	pF
Reverse Recovery Time	t <sub>rr</sub> (Note 3)	$I_F$ = 5.0 mA, $V_R$ = 6.0 V, $R_L$ = 100 $\Omega$ , $I_{rr}$ = 0.1 $I_R$	_	4.0	ns

<sup>3.</sup>  $t_{rr}$  Test Circuit on following page.

## TYPICAL ELECTRICAL CHARACTERISTICS

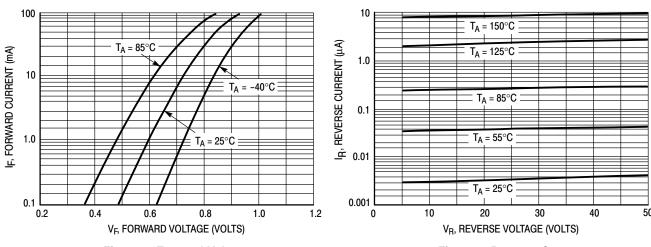


Figure 1. Forward Voltage

Figure 2. Reverse Current

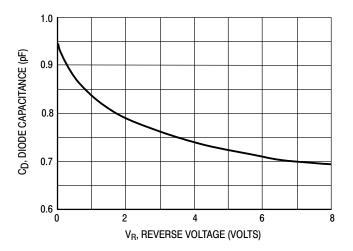


Figure 3. Diode Capacitance

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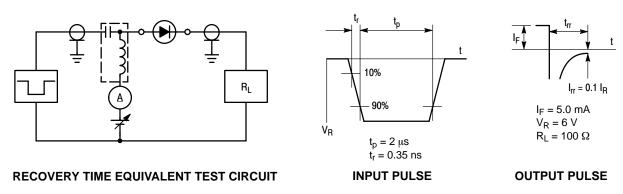
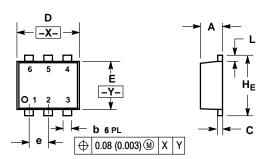


Figure 4. Reverse Recovery Time Test Circuit for the NSDEMN11XV6T1

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#### PACKAGE DIMENSIONS

SOT-563, 6 LEAD CASE 463A-01 ISSUE F

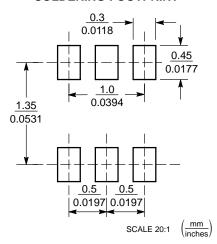


## NOTES

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: MILLIMETERS
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.50	0.55	0.60	0.020	0.021	0.023
b	0.17	0.22	0.27	0.007	0.009	0.011
С	0.08	0.12	0.18	0.003	0.005	0.007
D	1.50	1.60	1.70	0.059	0.062	0.066
Е	1.10	1.20	1.30	0.043	0.047	0.051
е	0.5 BSC			0.02 BSC		
L	0.10	0.20	0.30	0.004	0.008	0.012
HE	1.50	1.60	1.70	0.059	0.062	0.066

#### SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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